

YJ Planar Fast Recovery Diode Die Specification

600V 5A, Fast recovery diode die based on silicon planar process
Part No.: FRD05A600AS-290A

Main Products Characterstics

Maximum Ratings

Static Electrical Characteristics (Ta = 25°C)

Device Schematics and Outline Drawing

- Die Thickness
- Die Size *
- Top Metal Pad
- Active Area
- Top Metal
- Back Metal
- Note: 1 *: Cutting street width is around 40um

Important Notice

Specification apply to die only. Actual performance may degrade when assembled.

Recommended Storage Environment:

does not guarantee device performance after assembly.

Store in original container, in dessicated nitrogen, with no contamination.

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